Examiner-Initiated Interview Summary	Application No.	Applicant(s)
	09/732,928	SHIMAZU ET AL.
	Examiner	Art Unit
	James P. Hughes	2881
All Participants:	Status of Application: <u>Pending</u>	
(1) <u>James P. Hughes</u> .	(3)	
(2) <u>David Safran</u> .	(4)	
Date of Interview: 16 September 2003	Time: <u><i>AM</i></u>	
Type of Interview:		
Part I.		
Rejection(s) discussed:  Potential new limitaitons to claims 1 and 9 to overcome new rejections.	ctions based on IDS documents.	
Claims discussed:		
1 and 9		
Prior art documents discussed:		
Bohlen et al. "High Throughput Submicron Lithography with Elec Proximity Projection Lithography" that were submited in the IDS.	tron Beam Proximity Printing" and	d Utsumi "Low Energy e-beam
Part II.		
SUBSTANCE OF INTERVIEW DESCRIBING THE GENER		
An added limitation of "wherein, said plurality of masks comprise 9 was suggested by the examiner and rejected by applicant on S	at least two masks which are no ceptember 22, 2003.	n-complimentary" to claims 1 and
Part III.		
<ul> <li>☐ It is not necessary for applicant to provide a separate r directly resulted in the allowance of the application. The of the interview in the Notice of Allowability.</li> <li>☑ It is not necessary for applicant to provide a separate r did not result in resolution of all issues. A brief summar</li> </ul>	e examiner will provide a writh record of the substance of the	ten summary of the substance interview, since the interview
JOHN R. LEE SUPERVISORY PATENT EXAMINER JECHNOLOGY CENTER 2800		,
(Examiner/SPE Signature) (Applicant	/Applicant's Representative S	ignature – if appropriate)
(Application to the control of the c		.g